

Product specification Supersedes data of 1997 Jun 30 IC24 Data Handbook

1998 Jul 31



PHILIPS

## 74LVC543A

#### FEATURES

- 5-volt tolerant inputs/outputs, for interfacing with 5-volt logic
- Supply voltage range of 1.2V to 3.6V
- Complies with JEDEC standard no. 8-1A
- CMOS low power consumption
- Direct interface with TTL levels
- 8-bit octal transceiver with D-type latch
- Back-to-back registers for storage
- Separate controls for data flow in each direction
- 3-State non-inverting outputs for bus oriented applications
- High impedance when V<sub>CC</sub> = 0V

#### DESCRIPTION

The 74LVC543A is a high-performance, low-power, low-voltage, Si-gate CMOS device and superior to most advanced CMOS compatible TTL families.

The 74LVC543A is an octal registered transceiver containing two sets of D-type latches for temporary storage of the data flow in either direction. Separate latch enable ( $\overline{LE}_{AB}$ ,  $\overline{LE}_{BA}$ ) and output enable ( $\overline{OE}_{AB}$ ,  $\overline{OE}_{BA}$ ) inputs are provided for each register to permit independent control of inputting and outputting in either direction of the data flow.

The 74LVC543A contains eight D-type latches, with separate inputs and controls for each set. For data flow from A to B, for example, the A-to-B enable ( $\overline{E}_{AB}$ ) input must be LOW in order to enter data from  $A_0-A_7$  or take data from  $B_0-B_7$ , as indicated in the function table. With  $\overline{E}_{AB}$  LOW, a LOW signal on the A-to-B latch enable ( $\overline{LE}_{AB}$ ) input makes the A-to-B latches transparent; a subsequent LOW-to HIGH transition of the  $\overline{LE}_{AB}$  signal puts the A data into the latches where it is stored and the B outputs no longer change with the A inputs. With  $\overline{E}_{AB}$  and  $\overline{OE}_{AB}$  both low, the 3-state B output buffers are active and display the data present at the outputs of the A latches

### QUICK REFERENCE DATA

GND = 0V;  $T_{amb} = 25^{\circ}C$ ;  $T_{r} = T_{f} \le 2.5$ ns

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t <sub>PHL</sub> /t <sub>PLH</sub>	Propagation delay A <sub>n</sub> to B <sub>n</sub>	C <sub>L</sub> = 50 pF V <sub>CC</sub> = 3.3V	3.3	ns
Cl	input capacitance		5.0	pF
C <sub>I/O</sub>	input/output capacitance		10.0	pF
C <sub>PD</sub>	power dissipation capacitance per latch	$V_{CC} = 3.3V$	27	pF

NOTES:

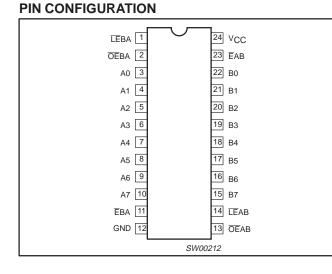
1. C<sub>PD</sub> is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W)

#### **ORDERING INFORMATION**

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG DWG. #
24-Pin Plastic Small Outline (SO)	–40°C to +85°C	74LVC543A D	74LVC543A D	SOT137-1
24-Pin Plastic Shrink Small Outline (SSOP) Type II	–40°C to +85°C	74LVC543A DB	74LVC543A DB	SOT340-1
24-Pin Plastic Thin Shrink Small Outline (TSSOP) Type I	–40°C to +85°C	74LVC543A PW	7LVC543APW DH	SOT355-1

<sup>1.</sup> C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> P<sub>D</sub> = C<sub>PD</sub> x V<sub>CC</sub><sup>2</sup> x f<sub>i</sub> +  $\Sigma$  (C<sub>L</sub> x V<sub>CC</sub><sup>2</sup> x f<sub>o</sub>) where: f<sub>i</sub> = input frequency in MHz; C<sub>L</sub> = output load capacity in pF; f<sub>o</sub> = output frequency in MHz; V<sub>CC</sub> = supply voltage in V;  $\Sigma$  (C<sub>L</sub> x V<sub>CC</sub><sup>2</sup> x f<sub>o</sub>) = sum of the outputs 2. The condition is V<sub>I</sub> = GND to V<sub>CC</sub>

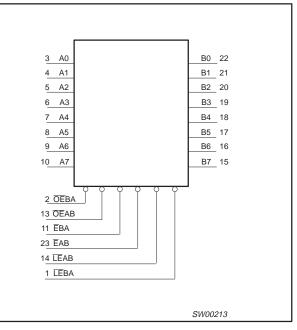
## 74LVC543A



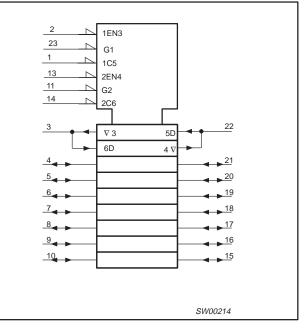
#### **PIN DESCRIPTION**

PIN NUMBER	SYMBOL	FUNCTION
1	LE <sub>BA</sub>	'B' to 'A' latch enable input (active LOW)
2	OE <sub>BA</sub>	'B' to 'A' output enable input (active LOW)
3,4,5,6, 7, 8, 9 10	A <sub>0</sub> to A <sub>7</sub>	'A' data inputs/outputs
11	Ē <sub>BA</sub>	'B' to 'A' enable input (active LOW)
12	GND	ground (0V)
22, 21, 20, 19, 18, 17, 16, 15	B <sub>0</sub> to B <sub>7</sub>	'B' data inputs/outputs
13	<u>OE</u> AB	'A' to 'B' output enable input (active LOW)
14	LEAB	'A' to 'B' latch enable input (active LOW)
23	Ē <sub>AB</sub>	'A' to 'B' enable input (active LOW)
24	V <sub>CC</sub>	positive supply voltage

#### LOGIC SYMBOL

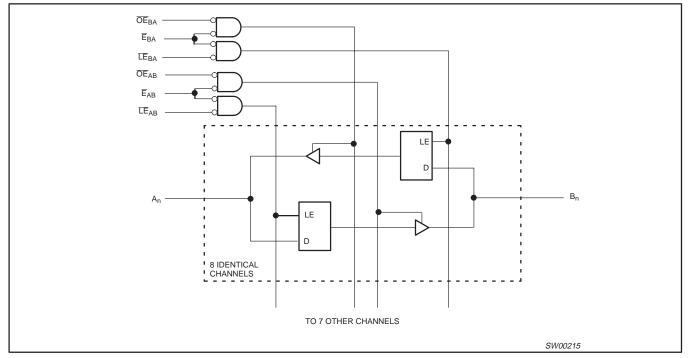


### LOGIC SYMBOL (IEEE/IEC)



## 74LVC543A

### LOGIC DIAGRAM



### **FUNCTION TABLE**

		INPUTS				
OPERATING MODES	OEXX	EXX	LEXX	DATA	OUTPUTS	
Disabled	н	Х	Х	Х	Z	
Disabled	Х	Н	Х	Х	Z	
Disabled + Latch	L	$\uparrow \uparrow$	L L	h I	Z Z	
Latch + Display	L	L	$\uparrow \uparrow$	h I	HL	
Transparent	L	L	L L	H L	HL	
Hold (do nothing)	L	L	Н	Х	NC	

#### NOTES:

L

ΧХ AB for A-to-B direction, BA for B-to-A direction =

- Н High voltage level =
- Low voltage level L =
- High state must be present one setup time before the Low-to-High transition of  $\overline{LE}_{AB}$ ,  $\overline{LE}_{BA}$ ,  $\overline{E}_{AB}$ ,  $\overline{E}_{BA}$ ,  $\overline{E}_{BA}$ ,  $\overline{E}_{AB}$ ,  $\overline{E}_{BA}$ ,  $\overline{E}_{AB}$ , h =
- =
- X ↑ Don't care =
- Low-to-High level transition =
- No change
- NC = Z = High impedance OFF state

### Product specification

# Octal D-type registered transceiver (3-State)

### 74LVC543A

### **RECOMMENDED OPERATING CONDITIONS**

SYMBOL	PARAMETER	CONDITIONS	LIM	UNIT	
STMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V <sub>CC</sub>	DC supply voltage (for max. speed performance)		2.7	3.6	V
V <sub>CC</sub>	DC supply voltage (for low-voltage applications)		1.2	3.6	V
VI	DC Input voltage range		0	5.5	V
V <sub>I/O</sub>	DC Output voltage range; output HIGH or LOW state		0	V <sub>CC</sub>	V
	DC input voltage range; output 3-State		0	5.5	V
T <sub>amb</sub>	Operating ambient temperature range in free-air		-40	+85	°C
t <sub>r</sub> , t <sub>f</sub>	Input rise and fall times	$V_{CC} = 1.2 \text{ to } 2.7 \text{V}$ $V_{CC} = 2.7 \text{ to } 3.6 \text{V}$	0 0	20 10	ns/V

#### **ABSOLUTE MAXIMUM RATINGS<sup>1</sup>**

In accordance with the Absolute Maximum Rating System (IEC 134)

Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	PARAMETER CONDITIONS		UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +6.5	V
I <sub>IK</sub>	DC input diode current	V <sub>1</sub> < 0	-50	mA
VI	DC input voltage	Note 2	-0.5 to +6.5	V
I <sub>OK</sub>	DC output diode current	$V_{O} > V_{CC} \text{ or } V_{O} < 0$	±50	mA
V	DC output voltage; output HIGH or LOW state	Note 2	-0.5 to V <sub>CC</sub> +0.5	V
V <sub>I/O</sub>	DC input voltage; output 3-State	Note 2	-0.5 to 6.5	V
۱ <sub>0</sub>	DC output source or sink current	$V_{O} = 0$ to $V_{CC}$	± 50	mA
I <sub>GND</sub> , I <sub>CC</sub>	DC V <sub>CC</sub> or GND current		±100	mA
T <sub>stg</sub>	Storage temperature range		-65 to +150	°C
P <sub>TOT</sub>	Power dissipation per package – plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)	above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	500 500	mW

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## 74LVC543A

### DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions voltages are referenced to GND (ground = 0V)

						LIMITS			
SYMBOL	PARAMETER TEST (		CONDITIONS		Temp = -40°C to +85°C				
					TYP <sup>1</sup>	MAX			
M		V <sub>CC</sub> = 1.2V		V <sub>CC</sub>			V		
VIH	HIGH level Input voltage	V <sub>CC</sub> = 2.7 to 3.6V		2.0			1		
		$V_{CC} = 1.2V$				GND	V		
VIL	LOW level Input voltage	V <sub>CC</sub> = 2.7 to 3.6V				0.8	1 <sup>v</sup>		
		$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -$	–12mA	V <sub>CC</sub> -0.5					
V <sub>OH</sub>	HIGH level output voltage	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -$	V <sub>CC</sub> -0.2	V <sub>CC</sub>		- V			
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} I_O = -$	V <sub>CC</sub> -0.6						
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} I_O = -$	V <sub>CC</sub> -0.8						
	$V_{CC} = 2.7V; V_I = V_{IH} \text{ or }$		12mA			0.40	V		
V <sub>OL</sub>	LOW level output voltage	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 1$		GND	0.20				
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 2$			0.55	1			
I <sub>I</sub>	Input leakage current	$V_{CC}$ = 3.6V; $V_{I}$ = 5.5V or GND	Not for I/O pins		±0.1	±5	μA		
I <sub>IHZ</sub> /I <sub>ILZ</sub>	Input current for common I/O pins	$V_{CC}$ = 3.6V; $V_{I}$ = 5.5V or GND	V <sub>CC</sub> = 3.6V; V <sub>I</sub> = 5.5V or GND		±0.1	±15	μA		
I <sub>OZ</sub>	3-State output OFF-state current	$V_{CC} = 3.6V; V_I = V_{IH} \text{ or } V_{IL}; V_O = 5.5V \text{ or } GND$			0.1	±10	μΑ		
I <sub>off</sub>	Power off leakage supply	$V_{CC} = 0.0V; V_{I} \text{ or } V_{O} = 5.5V$			0.1	±10	μA		
I <sub>CC</sub>	Quiescent supply current	$V_{CC}$ = 3.6V; $V_{I}$ = $V_{CC}$ or GND; $I_{O}$	= 0		0.1	10	μA		
$\Delta I_{CC}$	Additional quiescent supply current per input pin	$V_{CC} = 2.7V$ to 3.6V; $V_{I} = V_{CC} - 0.6$	6V; I <sub>O</sub> = 0		5	500	μΑ		

#### NOTE:

1. All typical values are at  $V_{CC}$  = 3.3V and  $T_{amb}$  = 25°C.

### AC CHARACTERISTICS

 $GND = 0V; t_r = t_f = 2.5ns; C_L = 50pF$ 

		LIMITS							
SYMBOL	PARAMETER	WAVEFORM	Vcc	$V_{CC}$ = 3.3V ±0.3V		V <sub>CC</sub> = 2.7V		V <sub>CC</sub> = 1.2V	
			MIN	TYP <sup>1</sup>	MAX	MIN	MAX	TYP	1
t <sub>PHL</sub> t <sub>PLH</sub>	Propagation delay $A_n$ to $B_n$ , $B_n$ to $A_n$	1, 5	1.5	3.3	7	1.5	8	13.0	ns
t <sub>PHL</sub> t <sub>PLH</sub>	Propagation delay $\overline{LE}_{BA}$ to $A_n$ , $\overline{LE}_{AB}$ to $B_n$ ,	2, 5	1.5	4.1	8.5	1.5	9.5	16.0	ns
t <sub>PZH</sub> t <sub>PZL</sub>	3-State output enable time $\overline{OE}_{BA}$ to $A_n$ , $\overline{OE}_{AB}$ to $B_n$ ,	3, 5	1.5	4.2	7.7	1.5	9.2	15.0	ns
t <sub>PHZ</sub> t <sub>PLZ</sub>	$\frac{3\text{-}State output disable time}{\overline{\text{OE}}_{BA} \text{ to } A_n, \overline{\text{OE}}_{AB} \text{ to } B_n,$	3, 5	1.5	3.4	7.0	1.5	7.5	8.0	ns
t <sub>PZH</sub> t <sub>PZL</sub>	3-State output enable time $\overline{E}_{BA}$ to $A_n$ , $\overline{E}_{AB}$ to $B_n$ ,	3, 5	1.5	4.4	8.0	1.5	9.3	15.0	ns
t <sub>PHZ</sub> t <sub>PLZ</sub>	3-State output disable time $\overline{E}_{BA}$ to $A_n$ , $\overline{E}_{AB}$ to $B_n$ ,	3, 5	1.5	3.6	7.0	1.5	7.5	8.0	ns
t <sub>W</sub>	$\overline{\text{LE}}_{XX}$ pulse width LOW	2	3.0	0.9	-	3.0	-	4.0	ns
t <sub>su</sub>	Set-up time $A_n/B_n$ to $\overline{LE}_{XX}$ , $A_n/B_n$ to $\overline{E}_{XX}$	4	1.5	-0.5	_	1.5	_	-1.5	ns
t <sub>h</sub>	Hold time $A_n/B_n$ to $\overline{LE}_{XX}$ , $A_n/B_n$ to $\overline{E}_{XX}$	4	1.5	0.6	-	1.5	-	2.0	ns

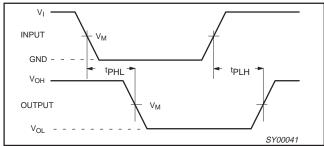
NOTE:

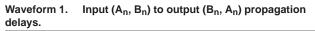
1. These typical values are at  $V_{CC}$  = 3.3V and  $T_{amb}$  = 25°C.

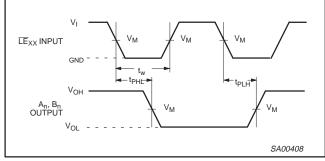
## 74LVC543A

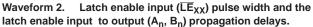
#### AC WAVEFORMS

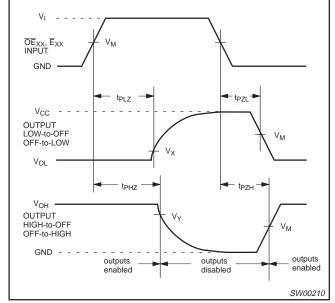
 $V_M$  = 1.5V at  $V_{CC} \geq 2.7V; V_M$  = 0.5  $V_{CC}$  at  $V_{CC} < 2.7V.$   $V_{OL}$  and  $V_{OH}$  are the typical output voltage drop that occur with the output load.  $V_X = V_{OL} + 0.3V$  at  $V_{CC} \geq 2.7V; V_X = V_{OL} + 0.1 V_{CC}$  at  $V_{CC} < 2.7V$   $V_Y = V_{OH} - 0.3V$  at  $V_{CC} \geq 2.7V; V_Y = V_{OH} - 0.1 V_{CC}$  at  $V_{CC} < 2.7V$ 



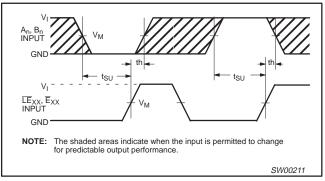






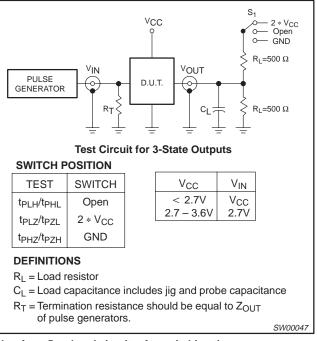


Waveform 3. 3-State enable and disable times



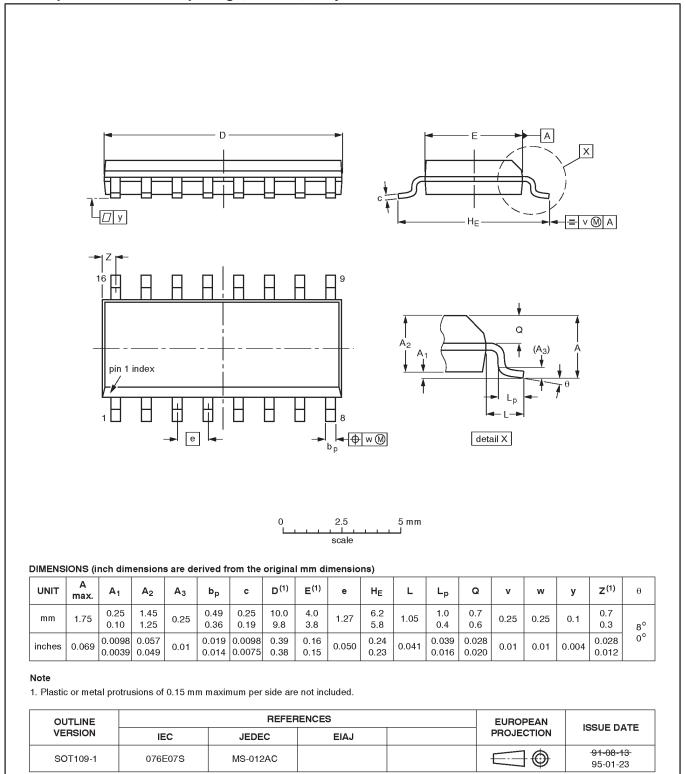
Waveform 4. Data setup and hold times for the  $(A_n, B_n)$  input to the  $\overline{LE}_{XX}$  and  $\overline{E}_{XX}$  inputs.

#### **TEST CIRCUIT**



Waveform 5. Load circuitry for switching times.

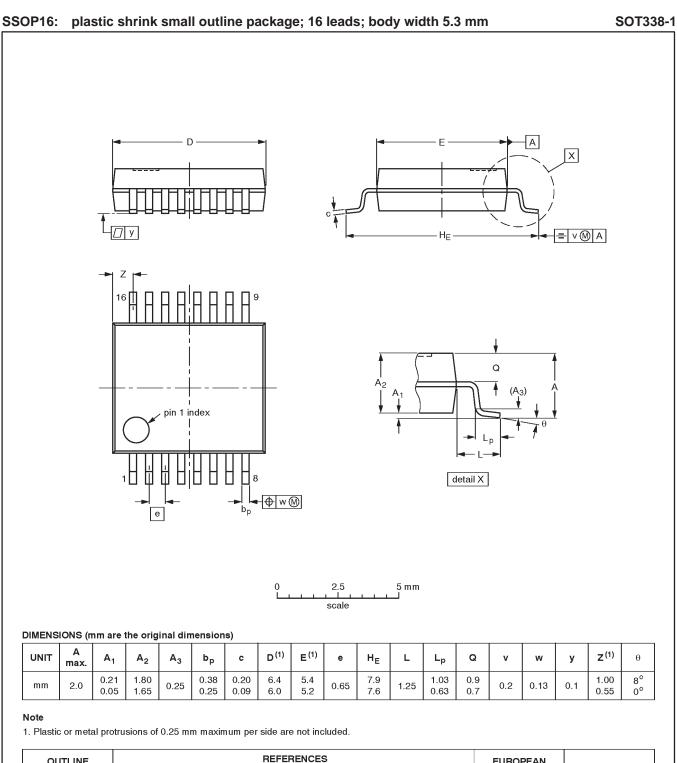
### SO16: plastic small outline package; 16 leads; body width 3.9 mm



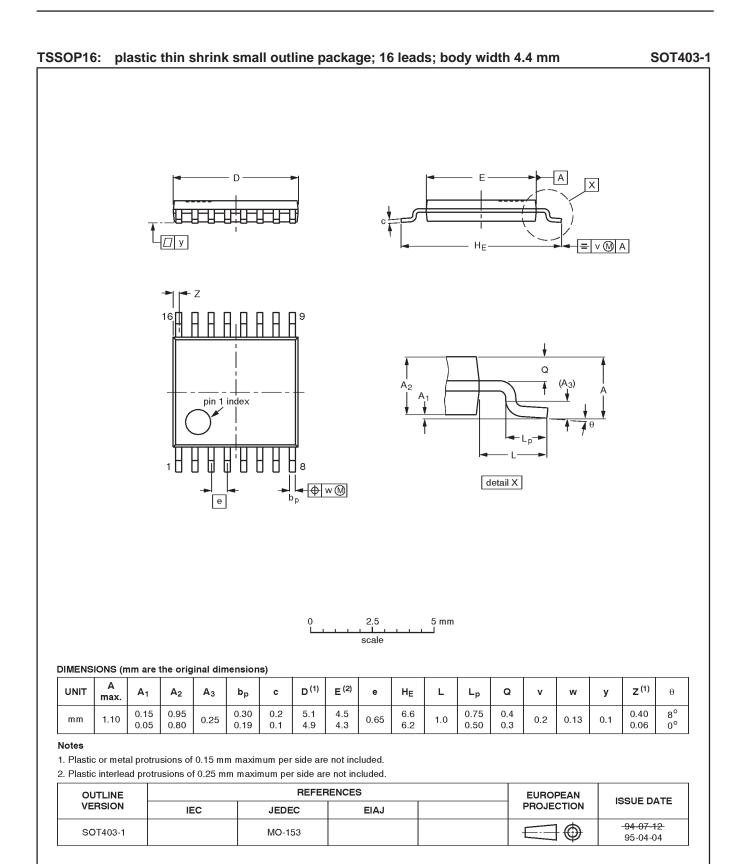
SOT109-1

### 74LVC543A

## 74LVC543A



### 74LVC543A



### Product specification

74LVC543A

# Octal D-type registered transceiver (3-State)

NOTES

## 74LVC543A

DEFINITIONS						
Data Sheet Identification	Definition					
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.				
Preliminary Specification Preproduction Product		This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.				
Product Specification Full Production		This data sheet contains Final Specifications. Philips Semiconductors reserves the right to make changes at any time without notice, in order to improve design and supply the best possible product.				

Philips Semiconductors and Philips Electronics North America Corporation reserve the right to make changes, without notice, in the products, including circuits, standard cells, and/or software, described or contained herein in order to improve design and/or performance. Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no license or title under any patent, copyright, or mask work right to these products, and makes no representations or warranties that these products are free from patent, copyright, or mask work right infringement, unless otherwise specified. Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

#### LIFE SUPPORT APPLICATIONS

Philips Semiconductors and Philips Electronics North America Corporation Products are not designed for use in life support appliances, devices, or systems where malfunction of a Philips Semiconductors and Philips Electronics North America Corporation Product can reasonably be expected to result in a personal injury. Philips Semiconductors and Philips Electronics North America Corporation customers using or selling Philips Semiconductors and Philips Electronics North America Corporation Products for use in such applications do so at their own risk and agree to fully indemnify Philips Semiconductors and Philips Electronics North America Corporation for any damages resulting from such improper use or sale.

Philips Semiconductors 811 East Arques Avenue P.O. Box 3409 Sunnyvale, California 94088–3409 Telephone 800-234-7381 Philips Semiconductors and Philips Electronics North America Corporation register eligible circuits under the Semiconductor Chip Protection Act. © Copyright Philips Electronics North America Corporation 1998 All rights reserved. Printed in U.S.A.

> print code Document order number:

Date of release: 05-96 9397-750-04511

Let's make things better.





Copyright © Each Manufacturing Company.

All Datasheets cannot be modified without permission.

This datasheet has been download from :

www.AllDataSheet.com

100% Free DataSheet Search Site.

Free Download.

No Register.

Fast Search System.

www.AllDataSheet.com